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ON Semiconductor®

# FDD9410-F085

# N-Channel Power Trench® MOSFET 40 V, 50 A, 4.1 m $\Omega$

#### **Features**

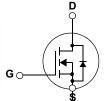
- Typ  $r_{DS(on)}$  = 3.5 m $\Omega$  at  $V_{GS}$  = 10V,  $I_D$  = 50 A
- $\blacksquare$  Typ Q<sub>g(tot)</sub> = 23.5 nC at V<sub>GS</sub> = 10V, I<sub>D</sub> = 50 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

#### **Applications**

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Integrated Starter/alternator
- Primary Switch for 12V Systems



G



D

(TO-252)

### **MOSFET Maximum Ratings** $T_J = 25$ °C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain to Source Voltage		40	V
V <sub>GS</sub>	Gate to Source Voltage	oltage		V
	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> = 25°C	50	^
I <sub>D</sub>	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure4	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	40	mJ
	Power Dissipation		75	W
$P_D$	Derate Above 25°C		0.5	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		2	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	52	°C/W

#### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD9410	FDD9410-F085	D-PAK(TO-252)	13"	12mm	2500 units

- 1: Current is limited by bondwire configuration.
- 2: Starting T<sub>J</sub> = 25°C, L = 50uH, I<sub>AS</sub> = 40A, V<sub>DD</sub> = 40V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche.

  3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

Units

Max

Тур

# **Electrical Characteristics** $T_J = 25^{\circ}C$ unless otherwise noted

**Parameter** 

Off Characteristics							
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V	<sub>'GS</sub> = 0V	40	-	-	V
1	Drain to Source Leakage Current	$V_{DS} = 40V$ ,	$T_{J} = 25^{\circ}C$	-	-	1	μΑ
IDSS		$V_{GS} = 0V$	$T_J = 175^{\circ}C(Note 4)$	-	-	1	mA
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

**Test Conditions** 

Min

#### On Characteristics

Symbol

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$		2.0	3.0	4.0	V
r <sub>DS(on)</sub>	Il Irain to Source (In Registance	I <sub>D</sub> = 50A,	$T_{J} = 25^{\circ}C$	-	3.5	4.1	$m\Omega$
		$V_{GS} = 10V$	$T_J = 175^{\circ}C(Note 4)$	-	6.1	7.1	$m\Omega$

## **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	-V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, -f = 1MHz		-	1715	-	pF
C <sub>oss</sub>	Output Capacitance			-	453	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	- 11VII 12			28	-	pF
$R_g$	Gate Resistance	f = 1MHz		-	2.3	-	Ω
$Q_{g(ToT)}$	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V	V <sub>DD</sub> = 20V	-	23.5	34.5	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 2V$ $I_D = 50A$		-	3.2	4	nC
$Q_{gs}$	Gate to Source Gate Charge		_	-	9.6	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge			-	4.4	-	nC

# **Switching Characteristics**

t <sub>on</sub>	Turn-On Time	$V_{DD}$ = 20V, $I_{D}$ = 50A, $V_{GS}$ = 10V, $R_{GEN}$ = $6\Omega$	-	-	38	ns
t <sub>d(on)</sub>	Turn-On Delay Time		-	12	1	ns
$t_r$	Rise Time		-	12	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	20	-	ns
t <sub>f</sub>	Fall Time		-	9	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	45	ns

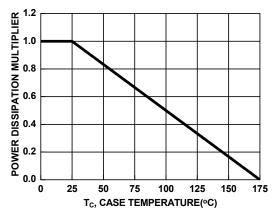
#### **Drain-Source Diode Characteristics**

$V_{SD}$	ISOURCE to Drain Diode Voltage	I <sub>SD</sub> = 50A, V <sub>GS</sub> = 0V	-	-	1.25	V
		$I_{SD} = 25A, V_{GS} = 0V$	-	-	1.2	V
T <sub>rr</sub>	Reverse Recovery Time	$I_F = 50A$ , $dI_{SD}/dt = 100A/\mu s$ ,	-	44	58	ns
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DD</sub> =32V	-	31.5	41	nC

#### Note:

4: The maximum value is specified by design at  $T_J$  = 175°C. Product is not tested to this condition in production.

## **Typical Characteristics**



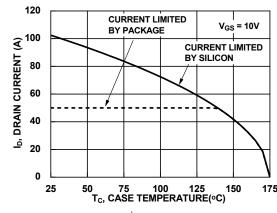


Figure 1. Normalized Power Dissipation vs. Case Temperature

Figure 2. Maximum Continuous Drain Current vs.
Case Temperature

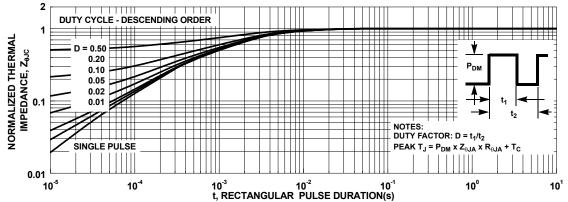


Figure 3. Normalized Maximum Transient Thermal Impedance

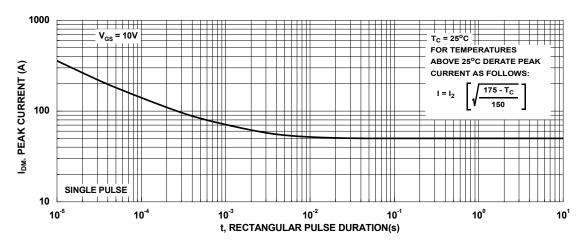


Figure 4. Peak Current Capability

# **Typical Characteristics**

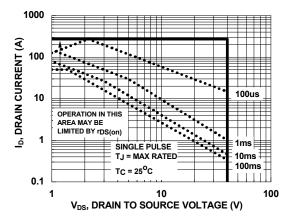
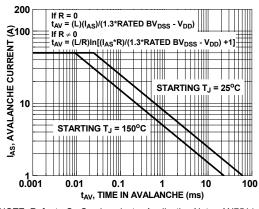


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to On Semiconductor Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

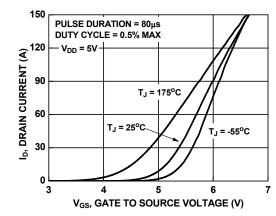


Figure 7. Transfer Characteristics

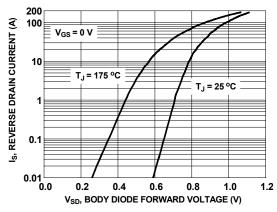


Figure 8. Forward Diode Characteristics

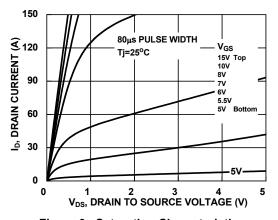


Figure 9. Saturation Characteristics

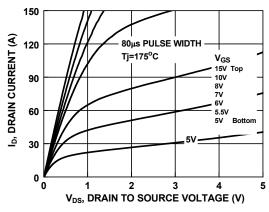


Figure 10. Saturation Characteristics

# **Typical Characteristics**

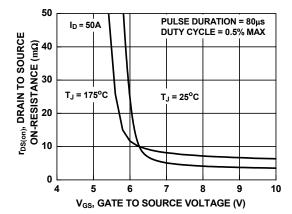


Figure 11. R<sub>DSON</sub> vs. Gate Voltage

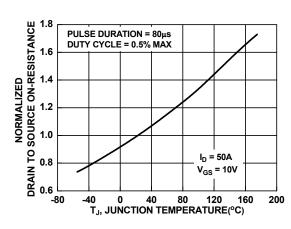


Figure 12. Normalized R<sub>DSON</sub> vs. Junction Temperature

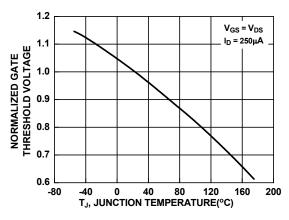


Figure 13. Normalized Gate Threshold Voltage vs. Temperature

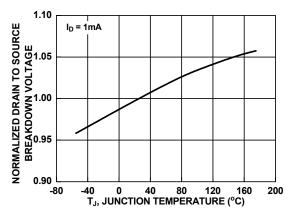


Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

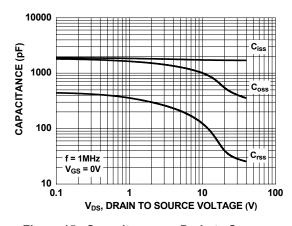


Figure 15. Capacitance vs. Drain to Source Voltage

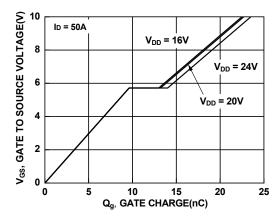


Figure 16. Gate Charge vs. Gate to Source Voltage

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